

TC7WZ32FU/FK

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

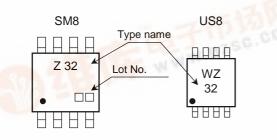
## TC7WZ32FU,TC7WZ32FK

2 Input or Gate

#### **Features**

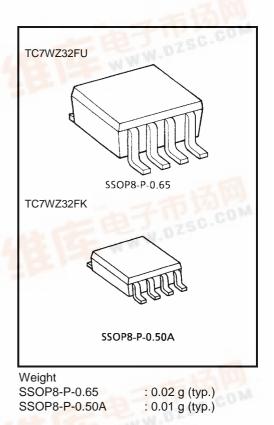
- High output drive: ±24 mA (min) @V<sub>CC</sub> = 3 V
- Super high speed operation:  $t_{pd} 2.4 \text{ ns} (typ.) @V_{CC} = 5 \text{ V}$ 50 pF
- Operation voltage range: VCC (opr) = 1.65~5.5 V • COM
- Latch-up performance: ±500 mA or more
- ESD performance: ±200 V or more (JEITA) • ±2000 V or more (MIL)
- Power down protection is provided on all inputs and outputs.
- Matches the performance of TC74LCX series when operated at 3.3 V VCC.

#### Marking

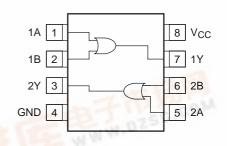


#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	-0.5~6	V
DC input voltage	VIN	-0.5~6	V
DC output voltage	V <sub>OUT</sub>	-0.5~6	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	I <sub>OK</sub>	-20	mA
DC output current	I <sub>OUT</sub>	±50	mA
DC V <sub>CC</sub> /ground current	ICC	±50	mA
Power dissipation	PD	300 (SM8) 200 (US8)	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C
Lead temperature (10s)	W.91	260	°C



#### Pin Assignment (top view)



## <u>TOSHIBA</u>

#### TC7WZ32FU/FK

#### **Truth Table**

# A B Y L L L L H H H L H H H H





#### **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit
Supply voltage	Vee	1.65~5.5	V
Supply voltage	Vcc	1.5~5.5 (Note 1)	
Input voltage	V <sub>IN</sub>	0~5.5	V
Output voltage	V <sub>OUT</sub>	0~5.5 (Note 2)	V
		0~V <sub>CC</sub> (Note 3)	v
Operating temperature	T <sub>opr</sub>	-40~85	°C
		0~20 (V_{CC} = 1.8 V $\pm$ 0.15 V, 2.5 V $\pm$ 0.2 V)	ns/V
Input rise and fall time	d <sub>t</sub> /d <sub>v</sub>	0~10 (V_{CC} = 3.3 V $\pm$ 0.3 V)	
		0~5 (V <sub>CC</sub> = 5.5 V $\pm$ 0.5 V)	

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state

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#### TC7WZ32FU/FK

#### **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol		Symbol				Ta = 25°C			Ta = -40~85°C		Unit
		Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit	
High level		VIH			1.65~ 1.95	$0.75 \\ \times V_{CC}$	_	_	$\begin{array}{c} 0.75 \\ \times  V_{CC} \end{array}$	_	
Input	VIH	_		2.3~5.5	$0.7 \\ \times V_{CC}$	_	_	$0.7 \\ \times V_{CC}$	_	V	
voltage Low level	VIL	_		1.65~ 1.95	_		$\begin{array}{c} 0.25 \\ \times \ V_{CC} \end{array}$	_	$\begin{array}{c} 0.25 \\ \times \ V_{CC} \end{array}$		
				2.3~5.5	_		$0.3 \\ \times \ V_{CC}$	_	$0.3 \\ \times  V_{CC}$		
					1.65	1.55	1.65		1.55		
				I <sub>OH</sub> = -100 μA	2.3	2.2	2.3		2.2		
				10H - 100 m/	3.0	2.9	3.0		2.9		
					4.5	4.4	4.5		4.4		
	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52		1.29		
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15		1.9		
				I <sub>OH</sub> = -16 mA	3.0	2.4	2.8		2.4		
			I <sub>OH</sub> = -24 mA	3.0	2.3	2.68		2.3	—		
Output				I <sub>OH</sub> = -32 mA	4.5	3.8	4.2		3.8	—	V
Voltage Low level				I <sub>OL</sub> = 100 μA	1.8	—	0	0.1	—	0.1	·
					2.3		0	0.1	—	0.1	-
					3.0		0	0.1		0.1	
	V <sub>OL</sub>	$V_{IN} = V_{IL}$		4.5		0	0.1		0.1		
			$I_{OL} = 4 \text{ mA}$	1.65		0.08	0.24		0.24		
			I <sub>OL</sub> = 8 mA	2.3		0.1	0.3		0.3		
				I <sub>OL</sub> = 16 mA	3.0		0.15	0.4		0.4	
				I <sub>OL</sub> = 24 mA	3.0		0.22	0.55		0.55	
			$I_{OL} = 32 \text{ mA}$	4.5		0.22	0.55		0.55		
Input leakage	e current	I <sub>IN</sub>	$V_{IN} = 5.5 V \text{ or GND}$		0~5.5			±1		±10	μA
Power off lea	Power off leakage current $I_{OFF}$ $V_{IN}$ or $V_{OUT} = 5.5$ V		JT = 5.5 V	0.0			1		10	μA	
Quiescent supply current $I_{CC}$ $V_{IN} = 5.5$ V or GND		ICC	V <sub>IN</sub> = 5.5 \	/ or GND	1.65~5.5			1		10	μA

## **TOSHIBA**

Characteristics	Cumpleal	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	t <sub>pLH</sub> t <sub>pHL</sub>	$C_L = 15 \text{ pF}, \text{ R}_L = 1 \text{ M}\Omega$	$1.8\pm0.15$	2.0	5.8	10.5	2.0	11.0	ns
			$\textbf{2.5}\pm\textbf{0.2}$	1.0	3.5	5.8	1.0	6.2	
			$\textbf{3.3}\pm\textbf{0.3}$	0.8	2.6	3.9	0.8	4.3	
			$5.0\pm0.5$	0.5	2.6	3.1	0.5	3.3	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$\textbf{3.3}\pm\textbf{0.3}$	1.2	3.2	4.8	1.2	5.2	
			$5.0\pm0.5$	0.8	2.4	3.7	0.8	4.0	
Input capacitance	C <sub>IN</sub>		0~5.5		3.0	_			pF
Power dissipation capacitance	C	(Note)	3.3		20	_			۶E
	C <sub>PD</sub>		5.5		26	_			pF

#### AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3 \text{ ns}$ )

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

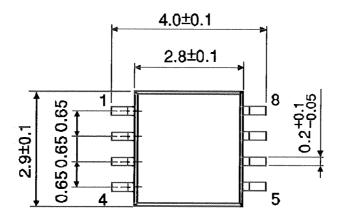
Average operating current can be obtained by the equation:  $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 

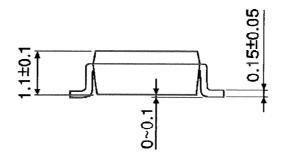
## **TOSHIBA**

#### Package Dimensions

SSOP8-P-0.65

Unit : mm





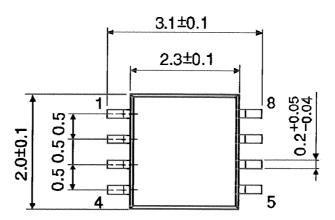
Weight: 0.02 g (typ.)

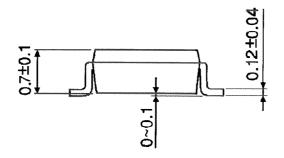
## <u>TOSHIBA</u>

#### Package Dimensions

SSOP8-P-0.50A

Unit : mm





Weight: 0.01 g (typ.)

### TOSHIBA

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